EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	4	"6733736"	US-PGPUB; USPAT	ADJ	ON	2008/06/04 13:28
L2	0	"7029643.pn"	US-PGPUB; USPAT	ADJ	ON	2008/06/04 13:29
L3	0	"7029643.pn"	US-PGPUB; USPAT	ADJ	ON	2008/06/04 13:29
L4	0	"7029643.pn."	US-PGPUB; USPAT	ADJ	ON	2008/06/04 13:29
L5	1	"7029643".pn.	US-PGPUB; USPAT	ADJ	ON	2008/06/04 13:29
L6	3	"6632761"	US-PGPUB; USPAT	ADJ	ON	2008/06/04 13:31
L7	1	"6387834".pn.	US-PGPUB; USPAT	ADJ	ON	2008/06/04 13:36
L8	90	bridgestone.as. and silicon carbide	US-PGPUB; USPAT	ADJ	ON	2008/06/04 13:37
L9	1	(09/941676).APP.	USPAT; USOCR	ADJ	ON	2008/06/04 13:40
L10	3	"7335330".pn. or "6632761".pn. or "6699411".pn.	USPAT; USOCR	ADJ	ON	2008/06/04 13:48
S1	13	US-6217969-$. DID. OR JP-05339057-$.DID. OR JP-02111663-$. DID. OR JP-6080295-$.DID. OR JP-04128369-$. DID. OR JP-08183661-$.DID. OR JP-05070230-$. DID. OR JP-11061394-$.DID.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/06/02 10:41
S2	2	JP-2000104161-$. DID.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/06/02 10:42
S3	9	((SHO) near2 (KUMAGAI)).INV.	US-PGPUB; USPAT	ADJ	ON	2008/06/02 10:42
S4	20	((FUMIO) near2 (ODAKA)).INV.	US-PGPUB; USPAT	ADJ	ON	2008/06/02 10:42

S5	42	((SHIGEKI) near2 (ENDO)).INV.	US-PGPUB; USPAT	ADJ	ON	2008/06/02 10:42
S6	340	refract$4 near3 index with ("4.16" or "4.10" or "4.00" or "3.9" or S3 or S2 or S1)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/02 11:14
S7	2	refract$4 near3 index with ("4.16" or "4.10" or "4.00" or "3.9" or S3 or S2 or S1) with (SIC or silicon carbide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/02 11:15
S8	21	refract$4 near3 index with ("4.16" or "4.10" or "4.00" or "3.9" or S3 or S2 or S1) with (SIC or silicon carbide or silicon)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/02 11:16
S9	654	refract$4 near3 index with (SIC or silicon carbide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/02 11:18
S10	7	refract$4 near3 index with (SIC or silicon carbide) same "633"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/02 11:19
S11	21	silicon carbide with target same volume	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/02 15:32
S12	8159	silicon carbide with silicon same volume	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/02 15:35

S13	124	silicon carbide with silicon same volume and "204"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/02 15:35
S14	8	silicon carbide with silicon same target same volume and "204"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/02 15:35
S15	287	silicon carbide same (particles or powder) same target	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/02 15:43
S16	23	silicon carbide same (particles or powder) same (micron or micrometer) same target	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/02 15:45
S17	5	silicon carbide with volume with target and "204"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/02 18:10
S18	13	silicon carbide with volume with target and sputter $3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 07:31
S19	240	silicon carbide with volume near3 ratio	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 07:59
S20	45	silicon carbide with volume near3 ratio with ("50" or "55" or "60" or "65" or "70")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 08:00

S21	45	silicon carbide with silicon with volume near3 ratio with ("50" or "55" or "60" or "65" or "70")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 08:21
S22	57	(SiC or silicon carbide) with (silicon or Si) with volume near3 ratio with ("50" or "55" or "60" or "65" or "70")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 08:21
S23	1	08-183661	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 09:06
S24	2	"08183661"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 09:06
S25	3	"05270917"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 09:08
S26	29	silicon carbide with impregnat$3 and "204"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 09:13
S27	25	silicon carbide with solvent with calcine$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 09:31
S28	1	(09/941676).APP.	USPAT; USOCR	ADJ	ON	2008/06/03 09:32

S29	0	silicon carbide with solvent with calcine$3 and target and sputter $3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 09:53
S30	1	silicon carbide with solvent same calcine$3 and target and sputter $3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 09:53
S31	1	silicon carbide same solvent same calcine$3 and target and sputter$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 09:53
S32	10	US-5589116-$. DID. OR US-5002000-$.DID. OR US-6228283-$. DID. OR US-4284431-$.DID. OR US-6217969-$. DID.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/06/03 10:13
S33	143	silicon carbide near3 target and sputter$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 10:14
S34	37	silicon carbide near3 target and sputter$3 and "204"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 10:15
S35	0	silicon carbide near3 slurry with dry$3 and sputter $3 and "204"/$. ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 10:37

S36	1	silicon carbide with slurry with dry $3 and sputter$3 and "204"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 10:37
S37	2	silicon carbide with slurry with dry $3 and "204"/$. ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 10:41
S38	2	silicon carbide with slurry same dry$3 and "204"/$. ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 10:42
S39	26	silicon carbide slurry same dry$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 10:43
S40	343	silicon carbide with slurry same dry$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 10:43
S41	0	refract$4 near3 index with (SiC or silicon carbide) with glass substrate same "633"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 11:51
S42	2	refract$4 near3 index same (SiC or silicon carbide) with glass substrate same "633"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 11:52
S43	9	refract$4 near3 index same (SiC or silicon carbide) with glass substrate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 11:52

S44	50	silicon carbide with volume near3 ("45" or "50" or "55" or "60" or "65" or "70" or "75") and sputter $3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 13:37
S45	21	silicon carbide with target same volume	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 13:38
S46	46	silicon carbide with volume near3 ("45" or "50" or "55" or "60" or "65" or "70" or "75") and sputter $3 not S45	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 13:38
S47	2	"5589116".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 14:46
S48	54	silicon carbide target with sputter $3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 16:01
S49	87	silicon carbide target	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 16:07
S50	33	silicon carbide target not S48	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 16:07

S51	1	weight near3 ration with impurit $3 with silicon	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 16:13
S52	130	weight near3 ratio with impurit$3 with silicon	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 16:13
S53	13	weight near3 ratio with impurit$3 with silicon with "0.01"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 16:14
S54	4	silicon near5 (weight near3 ratio) with impurit $3 with "0.01"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 16:17
S55	0	silicon near3 target near5 (weight near3 ratio) with impurit $3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 16:17
S56	41	silicon near5 (weight near3 ratio) with impurit $3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 16:17
S57	492	silicon carbide with volume and sputter$3 not S45	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 17:43
S58	213	silicon carbide near5 volume and sputter$3 not S45	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/03 17:44

| S59 | 49 | silicon carbide near5 volume near5 (ratio or percent) and sputter$3 not S45 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/06/03 17:44 |
| S60 | 50 | silicon carbide near5 volume near5 (ratio or percent$4) and sputter$3 not S45 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2008/06/03 17:45 |

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